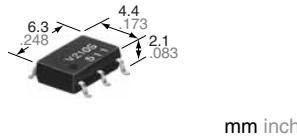
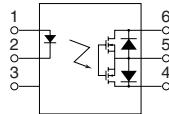


**Super miniature design,
SOP(1 Form A) 6-pin type.
Controls load voltage
60V to 400V**

**GU PhotoMOS
(AQV21OS)**



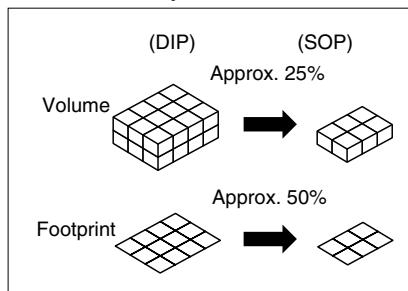
mm inch



FEATURES

1. 1 channel (Form A) in super miniature design

The device comes in a super-miniature SO package measuring (W) 4.4 x (L) 6.3 x(H) 2.1 mm (W) .173 x (L) .248 x(H) .083 inch —approx. 25% of the volume and 50% of the footprint size of DIP type PhotoMOS Relays.



2. Tape and reel

The device comes standard in a tape and reel (1,000 pcs./reel) to facilitate automatic insertion machines.

3. Controls low-level analog signals

PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

4. Low-level off state leakage current

In contrast to the SSR with an off state leakage current of several milliamperes, the PhotoMOS relay features a very small off state leakage current of typ. 100 pA even at the rated load voltage of 400 V (AQV214S).

TYPICAL APPLICATIONS

- Telephones
- Measuring instruments
- Computer
- Industrial robots
- High-speed inspection machines

TYPES

Type	Output rating*		Package size	Part No.		Packing quantity	
	Load voltage	Load current		Tube packing style	Tape and reel packing style	Tube	Tape and reel
AC/DC type	60V	500mA	SOP6pin	AQV212S	AQV212SX (Picked from the 1/2/3-pin side)	AQV212SZ (Picked from the 4/5/6-pin side)	1 tube contains: 75 pcs. 1 batch contains: 1,500 pcs.
	100V	300mA		AQV215S	AQV215SX (Picked from the 1/2/3-pin side)	AQV215SZ (Picked from the 4/5/6-pin side)	
	200V	160mA		AQV217S	AQV217SX (Picked from the 1/2/3-pin side)	AQV217SZ (Picked from the 4/5/6-pin side)	
	350V	120mA		AQV210S	AQV210SX (Picked from the 1/2/3-pin side)	AQV210SZ (Picked from the 4/5/6-pin side)	
	400V	100mA		AQV214S	AQV214SX (Picked from the 1/2/3-pin side)	AQV214SZ (Picked from the 4/5/6-pin side)	
	600V	40mA		AQV216S	AQV216SX (Picked from the 1/2/3-pin side)	AQV216SZ (Picked from the 4/5/6-pin side)	

* Indicate the peak AC and DC values.

Note: For space reasons, the initial letters of the part number "AQ" the package style indicator "X" or "Z" are not marked on the relay.
(Ex. the label for product number AQV214S is V214S)

GU PhotoMOS (AQV21OS)

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item	Symbol	Type of connection	AQV212S	AQV215S	AQV217S	AQV210S	AQV214S	AQV216S	Remarks	
Input	LED forward current	I _F		50 mA						
	LED reverse voltage	V _R		5 V						
	Peak forward current	I _{FP}		1 A					f = 100 Hz, Duty factor = 0.1%	
	Power dissipation	P _{in}		75 mW						
Output	Load voltage (peak AC)	V _L		60 V	100 V	200 V	350 V	400 V	600 V	
	Continuous load current	I _L		0.50 A	0.30 A	0.16 A	0.12 A	0.10 A	0.04 A	
				0.65 A	0.40 A	0.20 A	0.13 A	0.11 A	0.05 A	
				0.80 A	0.56 A	0.28 A	0.15 A	0.12 A	0.06 A	
	Peak load current	I _{peak}		1.0A	0.90A	0.48A	0.3 A	0.3 A	0.12 A	
	Power dissipation	P _{out}		450 mW						
Total power dissipation		P _T		500 mW						
I/O isolation voltage		V _{iso}		1,500 V AC						
Temperature limits	Operating	T _{opr}		-40°C to +85°C -40°F to +185°F					Non-condensing at low temperatures	
	Storage	T _{stg}		-40°C to +100°C -40°F to +212°F						

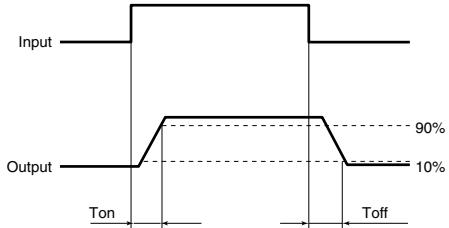
2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item	Symbol	Type of connection	AQV212S	AQV215S	AQV217S	AQV210S	AQV214S	AQV216S	Remarks	
Input	LED operate current	I _{Fon}	—	0.7 mA					I _L = Max.	
				3 mA						
	LED turn off current	I _{Foff}	—	0.4 mA					I _L = Max.	
				0.65 mA						
Output	LED dropout voltage	V _F	—	1.25 V (1.14 V at I _F = 5 mA)					I _F = 50 mA	
				1.5 V						
	On resistance	R _{on}	A	0.83 Ω	2.3 Ω	11 Ω	23 Ω	30 Ω	70 Ω	I _F = 5 mA I _L = Max. Within 1 s on time
				2.5 Ω	4.0 Ω	15 Ω	35 Ω	50 Ω	120 Ω	
	On resistance	R _{on}	B	0.44 Ω	1.15 Ω	5.5 Ω	11.5 Ω	22.5 Ω	55 Ω	I _F = 5 mA I _L = Max. Within 1 s on time
				1.25 Ω	2.0 Ω	7.5 Ω	17.5 Ω	25 Ω	100 Ω	
Transfer characteristics	Off state leakage current	R _{on}	C	0.25 Ω	0.6 Ω	2.8 Ω	6.0 Ω	11.3 Ω	28 Ω	I _F = 5 mA I _L = Max. Within 1 s on time
				0.63 Ω	1.0 Ω	3.8 Ω	8.8 Ω	12.5 Ω	50 Ω	
	Turn on time*	T _{on}	—	0.65 ms	0.60 ms	0.25 ms	0.25 ms	0.25 ms	0.25 ms	I _F = 5 mA V _L = Max.
	Turn off time			2.0 ms	2.0 ms	1.0 ms	0.5 ms	0.5 ms	0.5 ms	
	I/O capacitance	C _{iso}	—	0.08 ms 0.06 ms 0.05 ms 0.05 ms 0.05 ms 0.05 ms					I _F = 1 MHz V _b = 0 V	
				0.2 ms						
	Initial I/C isolation resistance	R _{iso}	—	0.8 pF 1.5 pF						
	Minimum			1,000 MΩ					500 V DC	

Note: Recommendable LED forward current I_F = 5mA.

For type of connection.

*Turn on/Turn off time



- For Dimensions.
- For Schematic and Wiring Diagrams.
- For Cautions for Use.